



PolarHV[™] HiPerFET IXFP 3N50PM Power MOSFET

(Electrically Isolated Tab)

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode

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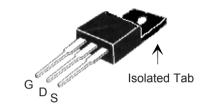
| Symbol | Test Conditions | Maximum | Ratings |
|---|--|----------|-----------|
| V _{DSS} | $T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}$ | 500 | V |
| V _{DGR} | $T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}; R_{GS} = 1 \text{ M}\Omega$ | 500 | |
| V _{GSS} | Continuous | ± 30 | V |
| V _{GSM} | Transient | ± 40 | |
| _{D25} _{DM} | $T_{\rm C} = 25^{\circ}$ C $T_{\rm C} = 25^{\circ}$ C, pulse width limited by $T_{\rm JM}$ | 2.7 8 | A A |
| I _{AR} | T _c = 25° C | 3 | A |
| E _{AR} | T _c = 25° C | 10 | mJ |
| E _{AS} | T _c = 25° C | 100 | mJ |
| dv/dt | $I_s \leq I_{DM}$, di/dt ≤ 100 A/ μ s, $V_{DD} \leq V_{DSS}$, $T_J \leq 150$ °C, $R_G = 50$ Ω | 10 | V/ns |
| $\overline{P_{D}}$ | T _c = 25° C | 36 | W |
| T _J | | -55 +150 | °C |
| T _{JM} | | 150 | °C |
| T _{stg} | | -55 +150 | °C |
| T _L | 1.6 mm (0.062 in.) from case for 10 s | 300 | °C |
| T _{SOLD} | Plastic body for 10 s | 260 | °C |
| M _d Weight | Mounting torque | 1.13/10 | Nm/lb.in. |

OVERMOLDED TO-220 (IXTP...M) OUTLINE

 $R_{DS(on)}$

≤

≤ 200 ns



G = Gate D = Drain S = Source

Features

- Plastic overmolded tab for electrical isolation
- Fast intrinsic diode
- ¹ International standard package
- Unclamped Inductive Switching (UIS) rated
- ¹ Low package inductance
 - easy to drive and to protect

| Symbol (Τ _J = 25° C, ι | Test Conditions unless otherwise specified) | | Ch Min. | istic Val Max | |
|--|--|-------------------------|------------|------------------|--------------------------|
| BV _{DSS} | V_{GS} = 0 V, I_{D} = 250 μ A | | 500 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_{D} = 250 \mu A$ | | 3.0 | 5.5 | V |
| GSS | $V_{GS} = \pm 30 \ V_{DC}, \ V_{DS} = 0$ | | | ±100 | nA |
| I _{DSS} | $V_{DS} = V_{DSS}$ $V_{GS} = 0 V$ | T _J = 125° C | | 5 200 | μ Α μ Α |
| R _{DS(on)} | V _{GS} = 10 V, I _D = 1.8 A Note 1 | | | 2.0 | Ω |

Advantages

- Easy to mount
- Space savings
- High power density

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| Symbo | ol Test Conditions CI $(T_J = 25^{\circ} \text{ C}, \text{ unless})$ Min. | | ristic Values ise specified) Max. |
|----------------------------|---|-----|---|
| g_{fs} | V _{DS} = 10 V; I _D = 1.8 A, Note 1 | 3.5 | S |
| C _{iss} |) | 409 | pF |
| C _{oss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$ | 48 | pF |
| C _{rss} | J | 6.1 | pF |
| t _{d(on)} | | 25 | ns |
| t _r | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_{D} = 3.6 \text{ A}$ | 28 | ns |
| $\mathbf{t}_{d(off)}$ | $R_{\rm G} = 50 \ \Omega (External)$ | 63 | ns |
| t _f |) | 29 | ns |
| $\mathbf{Q}_{g(on)}$ |) | 9.3 | nC |
| \mathbf{Q}_{gs} | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_{D} = 1.8$ | 3.3 | nC |
| \mathbf{Q}_{gd} | J | 3.4 | nC |
| R _{thJC} | | | 3.5 °C/W |

Source-Drain Diode

Characteristic Values (T₁ = 25° C unless otherwise specified)

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|---|---|--|------|---------------|--|
| Symbo | ol Test Conditions Min. | Тур. | Max. | | |
| Is | $V_{GS} = 0 V$ | | 3.6 | Α | |
| I _{SM} | Repetitive | | 5 | Α | |
| V _{SD} | $I_F = I_S$, $V_{GS} = 0$ V, Note 1 | | 1.5 | V | |
| t _{rr} Q _{RM} I _{RM} | $\begin{cases} I_F = 3.6 \text{ A, -di/dt} = 100 \text{ A/}\mu\text{s,} \\ V_R = 100 \text{ V, V}_{GS} = 0 \text{ V} \end{cases}$ | 0.1 0.5 | 200 | ns μC Α | |

ISOLATED TO-220 (IXTP...M) 0

Terminals: 1 - Gate

2 - Drain (Collector)

3 - Source (Emitter)

| MYZ | INCH | INCHES MI | | LIMETERS | |
|-----|----------|-----------|----------|----------|--|
| 21M | MIN | MAX | MIN | MAX | |
| Α | .177 | .193 | 4.50 | 4.90 | |
| A1 | .092 | .108 | 2.34 | 2.74 | |
| A2 | .101 | .117 | 2.56 | 2.96 | |
| b | .028 | .035 | 0.70 | 0.90 | |
| b1 | .050 | .058 | 1.27 | 1.47 | |
| С | .018 | .024 | 0.45 | 0.60 | |
| D | .617 | .633 | 15.67 | 16.07 | |
| E | .392 | .408 | 9.96 | 10.36 | |
| е | .100 BSC | | 2.54 BSC | | |
| Н | .255 | .271 | 6.48 | 6.88 | |
| L | .499 | .523 | 12.68 | 13.28 | |
| L1 | .119 | .135 | 3.03 | 3.43 | |
| ØΡ | .121 | .129 | 3.08 | 3.28 | |
| Q | .126 | .134 | 3.20 | 3.40 | |

Notes:

- 1) Pulse test, t \leq 300 μ s, duty cycle d \leq 2 %
- 2) Test current $I_{\tau} = 2.5 \text{ A}$

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.